L	Hits	Search Text	DB	Time stamp
Number				
5	141193	(substrate wafer) with (resistivity	USPAT;	2004/05/07
		resistan\$2)	US-PGPUB;	11:18
			EPO; JPO;	
			DERWENT;	i
			IBM TDB	
7	305	(buffer near2 (layer film)) with ((GaAs	USPAT;	2004/05/07
		and AlGaAs) ((Gallium near Aseni\$3) and	US-PGPUB;	11:22
		(Aluminum near Gallium near Aseni\$3)))	EPO; JPO;	
		with ((super adj lattice) superlattice	DERWENT;	
		super-lattice)	IBM TDB	
8	32	((substrate wafer) with (resistivity	USPAT;	2004/05/07
		resistan\$2)) and ((buffer near2 (layer	US-PGPUB;	11:22
		film)) with ((GaAs and AlGaAs) ((Gallium	EPO; JPO;	
		near Aseni\$3) and (Aluminum near Gallium	DERWENT;	
		near Aseni\$3))) with ((super adj lattice)	IBM TDB	
		superlattice super-lattice))		